Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.170 inches
Terminal Length:
0.975 inches
Overall Diameter:
Between 0.068 inches and 0.076 inches
Function For Which Designed:
Switching
Mounting Method:
Terminal
Features Provided:
Burn in and hermetically sealed case and electrostatic sensitive
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
10.00 microamperes forward current, average peak
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Precious Material And Location:
Terminal surfaces silver
Precious Material:
Silver
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0